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# A Wideband Microwave Double-Negative Metamaterial with Non-Foster Loading

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Abstract—Although the potential for wideband double-negative metamaterials using non-Foster circuit elements was described more than a decade ago, progress has been somewhat limited. Therefore, the analysis and simulation of a wideband microwave metamaterial are presented, where non-Foster elements are used as loads on split rings and on electric resonators. Using the Faraday law of induction, load conditions are derived for wideband negative permeability of a split ring. Using the Ampere circuital law, load conditions are derived for wideband negative permittivity of an electric resonator comprised of two disks connected by a rod. Simulations and extracted parameters confirm the underlying theory, and a wideband double-negative behavior is observed from 1.0 to 4.5 GHz for the proposed design.

#### I. Introduction

Metamaterials offer tremendous potential in a wide range of applications such as negative refraction, flat lenses, and cloaking [1]–[5]. Although there has been considerable progress in passive metamaterials, the bandwidth of these devices remains limited by the resonant behavior of the fundamental particles or unit cells comprising the metamaterial. In contrast, non-Foster circuit elements offer the possibility of achieving performance capabilities well beyond the reach of passive components. Although the theoretical potential for non-Foster elements to increase the bandwidth of negative-index metamaterials is well known, limited progress has been made in this area [6]. Recently, Hrabar et al. demonstrated non-Foster circuits in a split-ring resonator [7]. In addition, Kim et al., use shorted stubs on waveguides to achieve negative permeability and posts inside the waveguide to produce negative permittivity [8]. However, a complete wideband doublenegative metamaterial design has remained somewhat elusive.

To address these issues, a wideband double-negative metamaterial is proposed having simultaneous negative permittivity and negative permeability from 1.0 to 4.5 GHz. To achieve this, non-Foster loads are added to a single-split-ring resonator (SSRR) and to an electric disk resonator (EDR) comprised of two metal disks connected by a metal rod [9]. The design of the loads for the SSRR and EDR that comprise the unit cell are based on analysis of the coupled fields. The required negative inductance load of the SSRR is derived using Faraday's law of induction and the incident magnetic field. The required negative capacitance load of the EDR is derived using Ampere's circuital and the incident electric field. The results from Faraday's law and Ampere's law are then

used to compute the magnetic and electric dipole moments of the unit cell and to derive effective permittivity and permeability [10]. This straightforward analysis leads to a simple expression for the resulting negative effective permittivity and negative effective permeability of the unit cell as a function of frequency, with elimination of typical resonant behavior [1]. Thus, the proposed approach provides more direct insight into the interaction of the device with the electromagnetic field than may be offered by circuit-based approaches or models [11].

The following results and analyses address the problem of narrow bandwidth in double-negative metamaterials. In this, properly chosen non-Foster loads are shown to provide wideband negative effective permittivity, wideband negative effective permeability, and wideband double-negative metamaterials. In particular, the permeability of an SSRR becomes independent of frequency with a negative inductance load, and the permittivity of an EDR becomes independent of frequency with a negative capacitor load. Similar results for loop and dipole antennas were noted in [6].

In the following section, the design of a non-Foster-loaded SSRR with wideband negative permeability is first considered. The subsequent section considers the design of a non-Foster-loaded EDR with wideband negative permittivity. Finally, simulation results of wideband double-negative metamaterials are given, with effective permittivity and permeability extracted from the S-parameters of the metamaterial.

## II. WIDEBAND NEGATIVE PERMEABILITY ANALYSIS

The well-known theory of an elementary lossless split ring resonator is first considered, since it will be useful in describing the overall analysis approach for the proposed negative-permittivity metamaterials in the following section [1], [12]. Although other resonators may have advantages, they would unnecessarily complicate the basic development outlined here.

Consider the single-split-ring resonator (SSRR) in Fig. 1 that is expected to exhibit a typical narrowband resonant behavior. The dimensions of the unit cell comprising this magnetic metamaterial particle are  $l_x$ ,  $l_y$ , and  $l_z$ , and the split ring has an area  $A_R$ . As usual, the dimensions of the unit cell are considered significantly smaller than a wavelength. The incident magnetic field  $H_{\text{o}}\hat{\mathbf{x}}$  is parallel to the axis of the ring.

As shown in Fig. 1, the current in the split ring is defined as  $i_r$ , and the voltage across the gap is  $v_g$ . (This sign

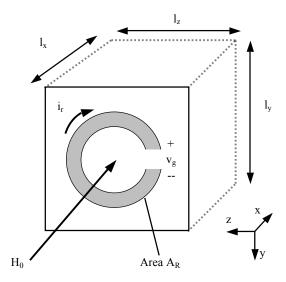


Fig. 1. Magnetic unit cell example showing single-split-ring resonator (SSRR).

convention for  $i_r$  and  $v_g$  is later convenient for describing the current through the capacitance of the gap in the ring.) Using Faraday's law of induction, the gap voltage is

$$v_g = -\frac{d\Phi_T}{dt} = -\frac{d\left(\Phi_0 + \Phi_R\right)}{dt} \,, \tag{1}$$

where  $\Phi_T$  is the total magnetic flux in the SSRR,  $\Phi_0 = \mu_0 H_0 A_R$  is the incident magnetic flux over the split ring,  $A_R$  is the area of the SSRR, and  $\Phi_R$  is the magnetic flux due to  $i_T$ . Then, the current in the ring is

$$i_r = C_g \frac{dv_g}{dt} = -C_g \frac{d^2 \left(\Phi_0 + \Phi_R\right)}{dt^2} , \qquad (2)$$

where  $C_g$  is the total capacitance across the gap of the SSRR. Taking the Laplace transform:

$$i_r = -s^2 C_q \left( \Phi_0 + \Phi_R \right) = -s^2 C_q \left( \Phi_0 + L_R i_r \right) ,$$
 (3)

where the self-inductance of the SSRR is  $L_R=\Phi_R/i_r$ . Solving for  $i_r$  yields the frequency-dependent current

$$i_r = -\Phi_0 \, \frac{s^2 C_g}{1 + s^2 L_R C_g} \, . \tag{4}$$

Next, consider replacing the gap capacitance  $C_g$  with a positive inductance  $L_g$  with reactance  $X_g = j\omega L_g$ . The voltage  $v_g$  now appears across this gap inductance  $L_g$ . Then, the current in the ring becomes

$$i_r = \frac{1}{L_g} \int v_g dt = -\frac{1}{L_g} \int \frac{d(\Phi_0 + \Phi_R)}{dt} dt .$$
 (5)

after substituting for  $v_g$  from (1). Taking the integral, and again with  $L_R = \Phi_R/i_r$ , leads to

$$i_r = -\frac{1}{L_a} \left( \Phi_0 + \Phi_R \right) = -\frac{1}{L_a} \left( \Phi_0 + L_R i_r \right) .$$
 (6)

Then, solving for  $i_r$  results in

$$i_r = -\Phi_0 \frac{1}{L_q + L_R} \ . {7}$$

Comparing (7) with (4), the ring current  $i_r$  in (7) no longer depends on frequency when the gap capacitance  $C_g$  is replaced by inductance  $L_g$ , allowing wideband behavior.

The current in the loop gives rise to a magnetic dipole moment in the SSRR of  $\mathbf{m} = i_r A_r \hat{\mathbf{x}}$ . The minus sign in (7) then results in  $\mathbf{m}$  having a direction opposite to the applied field  $H_{\circ}\hat{\mathbf{x}}$ . The macroscopic magnetization  $\mathbf{M}$  is then the magnetic dipole moment per unit volume:

$$\mathbf{M} = -\Phi_0 \frac{A_R}{l_x l_y l_z} \frac{1}{L_g + L_R} \,\hat{\mathbf{x}} = -\mu_0 H_0 \frac{A_R^2}{l_x l_y l_z} \frac{1}{L_g + L_R} \,\hat{\mathbf{x}}. \quad (8)$$

where the permeability of free space is  $\mu_0 = 1.26 \times 10^{-6}$  H/m, and for simplicity omitting mixing effects noted in [13]. With  $\mathbf{M} = \chi_m \mathbf{H}$  and  $\mu_r = 1 + \chi_m$ , it follows that

$$\mu_r = 1 - \mu_0 \frac{A_R^2}{l_x l_y l_z} \frac{1}{L_q + L_R} \,. \tag{9}$$

where  $\chi_m$  is the magnetic susceptibility, and  $\mu_r$  is the effective relative permeability of the metamaterial.

The proposed effective relative permeability  $\mu_r$  for the SSRR given in (9) does not vary with frequency and becomes a large negative value if  $L_g$  is chosen to be negative such that the denominator has  $(L_g + L_R) > 0$  and  $(L_g + L_R) \approx 0$ . Thus, a negative inductor load in the gap of a SSRR can provide wideband negative effective permeability. The desired condition  $(L_g + L_R) > 0$  has the same form as a series combination of a negative inductor with a positive inductor whose resulting inductance remains positive [14]. Non-Foster circuits such as a negative inductor can be designed using negative impedance converters, where recent progress has been made in potential stability issues [14], [15].

# III. WIDEBAND NEGATIVE PERMITTIVITY ANALYSIS

Just as the theory of the SSRR was developed above for wideband negative-permeability metamaterials, a similar approach is now used to develop the theory for the proposed wideband negative-permittivity metamaterials. The analysis follows along similar lines as the analysis of the magnetic unit cell of Fig. 1 [9].

Consider the electric disk resonator (EDR) in Fig. 2, resembling a three-dimensional version of the I-shaped structures in [10] and [16]. The dimensions of the unit cell comprising this electric metamaterial particle are the same as the magnetic component of Fig. 1,  $l_x$ ,  $l_y$ , and  $l_z$ . The metal disks near the top and bottom faces of the structure have areas  $A_D$ , and are connected together by a metal post with inductance  $L_p$ . As usual, the dimensions of the unit cell are taken to be less than a wavelength, so that the incident electric field  $E_0\hat{\mathbf{y}}$  is uniform over the unit cell. As shown in Fig. 2, the current in the post that connects the two disks is  $i_p$ , and the voltage between the upper and lower disk is  $v_d$ .

Using Ampere's circuital law and the Maxwell-Ampere equation, the time derivative of the total electric flux impinging

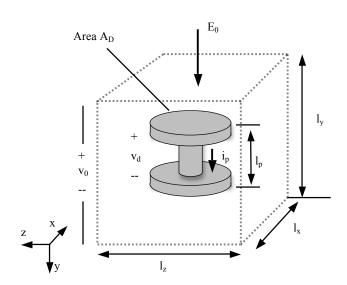


Fig. 2. Electric unit cell example showing electric disk resonator (EDR) comprised of two metal disks connected by a cylindrical metal post of length  $l_p$  with inductance  $L_p$ .

upon the top face of the upper disk equals the current in the post plus the time derivative of total electric flux departing the bottom face of the top disk [9]:

$$i_p + \frac{d}{dt}\Psi_F = \frac{d}{dt}\Psi_T , \qquad (10)$$

where  $i_p$  is the current in the post,  $\Psi_T$  is the total electric flux in coulombs impinging upon the top face of the upper disk of the EDR from sources external to the unit cell, and  $\Psi_F$  is the total electric flux that couples between the upper and lower EDR disks (i.e., internal to the unit cell). The left side of (10) then represents the total current (both circuit current and displacement current) flowing from the top disk to the bottom disk, and the right side represents the total displacement current coming from sources external to the unit cell and impinging on the top disk of the EDR.

As noted in [9], the internal electric flux  $\Psi_F$  can be represented by a capacitance  $C_F$  driven by the voltage  $v_d$  across the two disks, and the external electric flux  $\Psi_T$  can be represented by a capacitance  $C_0$  coupling to the external voltage potential across the unit cell  $v_0 = E_0 l_y$ , where  $E_0 \hat{\mathbf{y}}$  is the incident electric field. Then, (10) becomes:

$$i_p = \frac{d}{dt} (v_0 C_0 - \Psi_F) = \frac{d}{dt} (v_0 C_0 - v_d C_F) ,$$
 (11)

where capacitance  $C_F$  can also be thought of as a leakage capacitance or fringe capacitance around the post inductance.

The voltage between the two disks also equals the voltage across the inductive post, so:

$$v_d = L_p \frac{di_p}{dt} = L_p \frac{d^2}{dt^2} \left( v_0 C_0 - v_d C_F \right) ,$$
 (12)

where  $v_d$  is the voltage from the top disk to the bottom disk as before, and  $L_p$  is the inductance of the metal post connecting

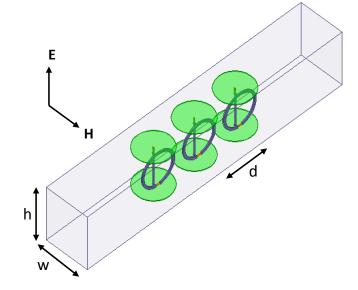


Fig. 3. Double-negative structure consisting of 3 SSRR and 3 EDR devices. EDR disks are shown in green and SRR rings in gray. The gaps in the SSRR rings are 1mm, and there is a 1 mm gap at the top of each EDR post. The non-Foster elements are modeled in these gaps in the SSRR and EDR devices.

the two disks. Taking the Laplace transform results in

$$v_d = s^2 L_p \left( v_0 C_0 - v_d C_F \right). \tag{13}$$

Solving for the voltage  $v_d$  then gives

$$v_d = v_0 \frac{s^2 L_p C_0}{1 + s^2 L_p C_F} \ . \tag{14}$$

Next, consider replacing the inductive post  $L_p$  with a positive capacitance  $C_p$  with reactance  $X_p = -j/(\omega C_p)$ . The current  $i_p$  then flows through this capacitance and the voltage  $v_d$  now appears across this capacitance, so:

$$v_d = \frac{1}{C_p} \int i_p \, dt = \frac{1}{C_p} \int \frac{d}{dt} \left( v_0 C_0 - v_d C_F \right) \, dt.$$
 (15)

after substituting for  $i_p$  from (11). Simplifying and solving for  $v_d$  results in

$$v_d = \frac{1}{C_p} \left( v_0 C_0 - v_d C_F \right) = v_0 \frac{C_0}{C_p + C_F} \,. \tag{16}$$

Comparing (16) with (14), note that the voltage  $v_d$  in (16) no longer depends on frequency when the post inductance  $L_p$  is replaced by  $C_p$ , thus allowing wideband behavior.

The charge on the disks then gives rise to an electric dipole moment:

$$\mathbf{p} = q l_p \; \hat{\mathbf{y}} = v_d C_p l_p \; \hat{\mathbf{y}} = v_0 C_0 l_p \frac{C_p}{C_p + C_F} \; \hat{\mathbf{y}} \; . \tag{17}$$

where  $\pm q$  is the charge in coulombs on the disks,  $\mathbf{p}$  is the electric dipole moment in the same direction as the applied field  $E_0\hat{\mathbf{y}}$ , and  $l_p$  is the distance between the two disks. In (17), the charge on the bottom disk is  $q = \int i_p dt$  and

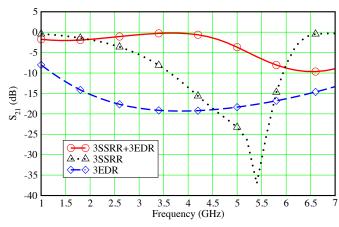


Fig. 4. Simulation results. The solid red curve with circles shows  $|S_{21}|$  in dB for the entire structure of Fig. 3. For comparison, the simulated  $|S_{21}|$  of only the three EDR structures with negative permittivity is shown in the dashed blue curve with diamonds, and the simulated  $|S_{21}|$  of only three SSRR structures with negative permeability is shown in the dotted black lines with triangles.

 $v_d = (1/C_p) \int i_p dt$ , so  $q = v_d C_p$ . Then, polarization **P** equals electric dipole moment per unit volume:

$$\mathbf{P} = \frac{\mathbf{p}}{l_x l_y l_z} = E_0 \frac{C_0 l_p}{l_x l_z} \left( \frac{C_p}{C_p + C_F} \right) \hat{\mathbf{y}}. \tag{18}$$

after subtituting  $E_0 l_y = v_0$ , and for simplicity omitting mixing effects noted in [13]. With  $\mathbf{P} = \chi_e \epsilon_{\circ} \mathbf{E}$  and  $\epsilon_r = 1 + \chi_e$ , the relative permittivity  $\epsilon_r$  is

$$\epsilon_r = 1 + \frac{C_0 l_p}{\epsilon_0 l_x l_z} \left( \frac{C_p}{C_p + C_F} \right), \tag{19}$$

where  $\chi_e$  is the electric susceptibility,  $\epsilon_r$  is the effective relative permittivity of the metamaterial, and  $\epsilon_o = 8.85 \times 10^{-12}$  F/m is the permittivity of free space.

Therefore, the effective relative permittivity  $\epsilon_r$  of the EDR in (19) does not vary with frequency, just as there was no frequency dependence in  $\mu_r$  for the SSRR result of (9) . The effective permittivity  $\epsilon_r$  becomes a large negative value if  $C_p$  is chosen to be negative such that the denominator has  $C_p + C_F \approx 0$  and  $C_p + C_F > 0$ . Thus, a negative capacitor load replacing the post of an EDR can provide wideband negative effective permittivity. The desired condition  $C_p + C_F > 0$  has the same form as a parallel combination of a negative capacitor with a positive capacitor whose resulting capacitance remains positive [14]. Non-Foster circuits such as a negative capacitor can be designed using negative impedance converters, where recent progress has been made in potential stability issues [14], [15]. Furthermore, in some applications metamaterials do not necessarily need to exhibit negative permittivity and permeability, since devices with non-negative refractive index less than unity or near zero can also be useful.

### IV. SIMULATION RESULTS

The wideband double-negative metamaterial test structure shown in Fig. 3 was chosen to illustrate the performance of the proposed design. The structure consists of three unit

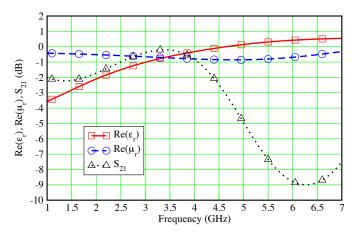


Fig. 5. Extracted values of the real parts of  $\mu_T$  and  $\epsilon_T$  for the three unit cell structure shown in Fig. 3. The effective permittivity is shown in the solid red curve with squares and the effective permeability is shown in the dashed blue curve with circles, both on a linear scale. For reference, the magnitude of  $S_{21}$  in dB is also shown in the dotted black curve with triangles.

cells within a parallel-plate waveguide with perfect electric conductor top and bottom walls separated by  $h=10\,\mathrm{mm}$ , and perfect magnetic conductor side walls separated by  $w=8\,\mathrm{mm}$ . The separation between unit cells was  $d=8\,\mathrm{mm}$ . The SSRR had a radius of 3.2 mm with a 1 mm gap, and the EDR was comprised of two disks 7 mm apart with 3.2 mm radius and a connecting post of 0.15 mm radius. The EDR and SSRR were centered within the waveguide, with 1 mm space between the EDR post and SSRR ring. Each EDR has a 1 mm gap in its post with a negative capacitance of  $C_p=-240\,\mathrm{fF}$  placed in the gap. Each SSRR has a 1 mm gap in its ring with a negative inductance of  $L_p=-10\,\mathrm{nH}$  placed in the gap. In addition, a negative capacitance of -45 fF was placed in parallel to  $L_p$  to compensate for stray capacitance in the ring to help improve bandwidth.

The structure of Fig. 3 was tested in the HFSS 3D electromagnetic simulator. Fig. 4 shows the simulation results for  $S_{21}$  for three cases. The solid red curve with circles in Fig. 4 shows  $|S_{21}|$  in dB for the entire structure of Fig. 3, and shows wideband double-negative behavior with less than 2 dB loss from 1.0 to 4.5 GHz. The dotted black curve with triangles shows  $|S_{21}|$  for the three SSRR devices, with the three EDR devices removed. In the dotted black curve, the insertion loss is due to the negative permeability of the three SSRR devices alone. The dashed blue curve with diamonds shows  $|S_{21}|$  for the three EDR devices, with the three SSRR devices removed. In the dashed blue curve, the insertion loss is due to the negative permittivity of the three EDR devices alone.

The effective permeability and effective permittivity of the three unit cell structure of Fig. 3 were extracted from the S-parameters of Fig. 4, drawing upon common methods such as outlined in [17] and [18]. Fig. 5 shows the real part of the effective permittivity (solid red curve with squares) and the real part of the effective permeability (dashed blue curve with circles), both on a linear scale. The dotted black curve with triangles shows  $|S_{21}|$  in dB for reference. Note

that both the permittivity  $\epsilon_r$  and permeability  $\mu_r$  remain negative from 1.0 to 4.5 GHz. Near 1 GHz,  $\epsilon_r$  approaches -3.5 while  $\mu_r$  approaches -0.3. Near 5 GHz,  $\epsilon_r$  becomes positive while  $\mu_r$  remains negative, suggesting an evanescent non-propagating condition above 4.5 GHz. Also, the attenuation greatly increases above 5 GHz as would be expected when  $\epsilon_r$  becomes positive while  $\mu_r$  remains negative.

#### V. CONCLUSION

Analysis and simulation results for the proposed non-Foster metamaterial confirm wideband double-negative behavior. Effective permittivity and permeability were extracted from Sparameters and confirm simultaneous negative permittivity and negative permeability from 1.0 to 4.5 GHz.

#### ACKNOWLEDGMENT

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